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Vishay Semiconductors

High Speed Infrared Emitting Diodes, 890 nm, **Surface Emitter Technology**





DESCRIPTION

As part of the SurfLight™ portfolio, the VSMY2890 series are infrared, 890 nm emitting diodes based on GaAlAs surface emitter chip technology with extreme high radiant intensities, high optical power and high speed, molded in clear, untinted plastic packages (with lens) for surface mounting (SMD).

APPLICATIONS

- · Automotive sensors
- Photointerrupters
- Emitter source for proximity sensors
- IR illumination

FEATURES

· Package type: surface-mount · Package form: GW, RGW

• Dimensions (L x W x H in mm): 2.3 x 2.3 x 2.8

AEC-Q101 qualified

• Peak wavelength: $\lambda_p = 890 \text{ nm}$

• Angle of half intensity: $\varphi = \pm 10^{\circ}$

• Suitable for high pulse current operation

· Terminal configurations: gullwing or reverse gullwing

 Package matches with detector VEMD2500X01 series

Floor life: 4 weeks, MSL 2a, according to J-STD-020

· Material categorization: for definitions of compliance please see www.vishav.com/doc?99912







FREE **GREEN**

PRODUCT SUMMARY				
COMPONENT	I_e (mW/sr) at I_F = 100 mA	φ (°)	$\lambda_{\mathbf{P}}$ (nm)	t _r (ns)
VSMY2890RGX01	135	± 10	890	15
VSMY2890GX01	135	± 10	890	15

Note

· Test conditions see table "Basic Characteristics"

ORDERING INFORMATION				
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM	
VSMY2890RGX01	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Reverse gullwing	
VSMY2890GX01	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Gullwing	

· MOQ: minimum order quantity



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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Forward current		I _F	100	mA
Peak forward current	$t_p/T = 0.5, t_p = 100 \mu s$	I _{FM}	200	mA
Surge forward current	t _p = 100 μs	I _{FSM}	1	А
Power dissipation		P _V	190	mW
Junction temperature		Tj	100	°C
Operating temperature range		T _{amb}	-40 to +85	°C
Storage temperature range		T _{stg}	-40 to +100	°C
Soldering temperature	According to Fig. 9, J-STD-020	T _{sd}	260	°C
Thermal resistance junction-to-ambient	JESD51	R_{thJA}	250	K/W

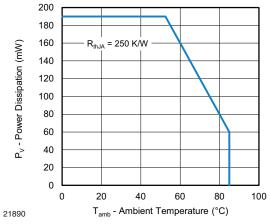


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

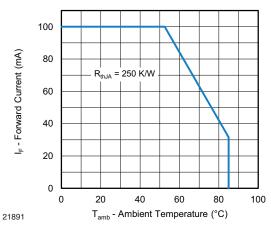


Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	V_{F}	-	1.7	1.9	V
Forward voltage	$I_F = 1 \text{ A}, t_p = 100 \ \mu\text{s}$	V _F	-	2.8	-	V
Temperature coefficient of V _F	I _F = 100 mA	TK _{VF}	-	-2.0	-	mV/K
Reverse current		I _R	Not designed for reverse operation μA		μΑ	
Junction capacitance	$V_R = 0 \text{ V}, f = 1 \text{ MHz}, E = 0 \text{ mW/cm}^2$	CJ	-	60	-	pF
Radiant intensity	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	l _e	50	135	175	mW/sr
nation intensity	$I_F = 1 \text{ A}, t_p = 100 \ \mu\text{s}$	l _e	-	1000	-	mW/sr
Radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	фe	-	55	-	mW
Temperature coefficient of radiant power	I _F = 100 mA	TKφe	-	-0.12	-	%/K
Angle of half intensity		φ	-	± 10	-	0
Peak wavelength	I _F = 100 mA	λ_{p}	870	890	910	nm
Spectral bandwidth	I _F = 100 mA	Δλ	-	35	-	nm
Temperature coefficient of λ _p	I _F = 100 mA	TKλ _p	-	0.3	-	nm/K
Rise time	I _F = 100 mA, 10 % to 90 %	t _r	-	15	-	ns
Fall time	I _F = 100 mA, 10 % to 90 %	t _f	-	15	-	ns

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

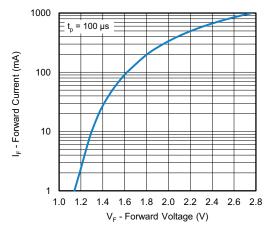
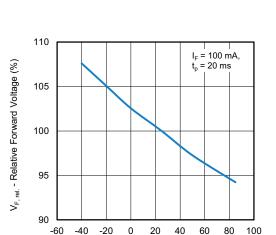


Fig. 3 - Forward Current vs. Forward Voltage



 T_{amb} - Ambient Temperature (°C) Fig. 4 - Relative Forward Voltage vs. Ambient Temperature

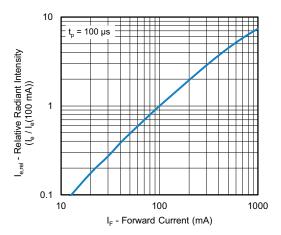


Fig. 5 - Relative Radiant Intensity vs. Forward Current

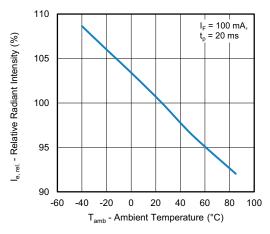


Fig. 6 - Relative Radiant Intensity vs. Ambient Temperature

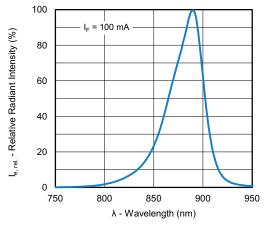


Fig. 7 - Relative Radiant Intensity vs. Wavelength

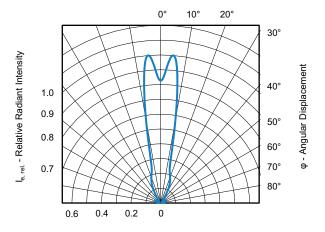


Fig. 8 - Relative Radiant Intensity vs. Angular Displacement

SOLDER PROFILE

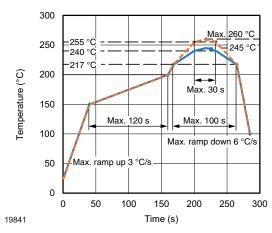


Fig. 9 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020

DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

FLOOR LIFE

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 4 weeks

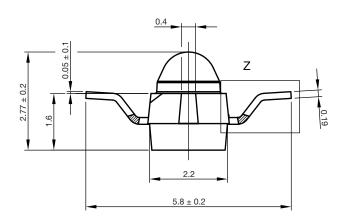
Conditions: T_{amb} < 30 °C, RH < 60 %

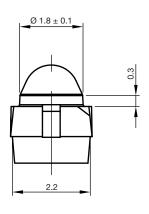
Moisture sensitivity level 2a, according to J-STD-020.

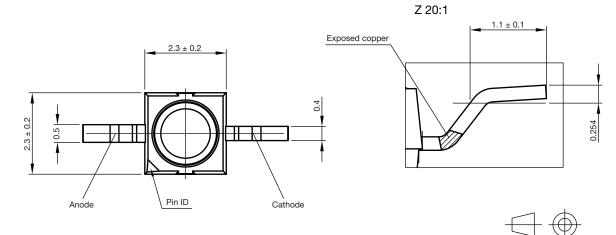
DRYING

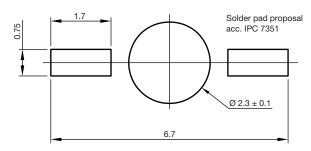
In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-033D or label. Devices taped on reel dry using recommended conditions 192 h at 40 $^{\circ}$ C (+ 5 $^{\circ}$ C), RH < 5 $^{\circ}$ M.

PACKAGE DIMENSIONS in millimeters: VSMY2890RGX01





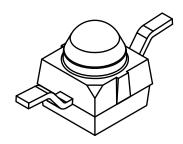




Not indicated tolerances ± 0.1

technical drawings

according to DIN specifications

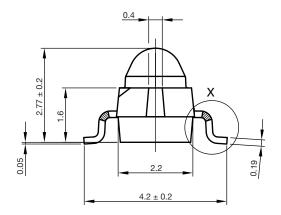


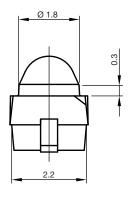
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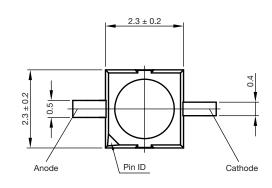
Issue: 1; 18.03.10

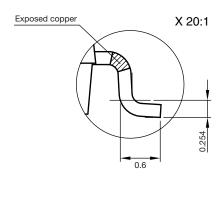
22100

PACKAGE DIMENSIONS in millimeters: VSMY2890GX01

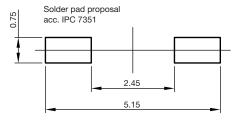




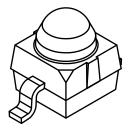








Not indicated tolerances ± 0.1

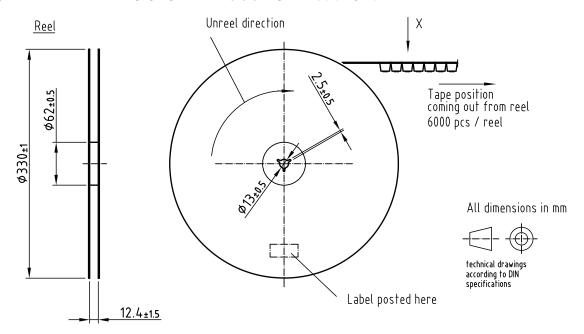


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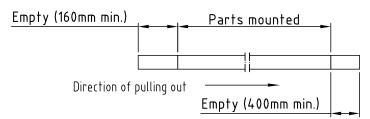
Issue: 1; 18.03.10

22099

TAPING AND REEL DIMENSIONS in millimeters: VSMY2890RGX01

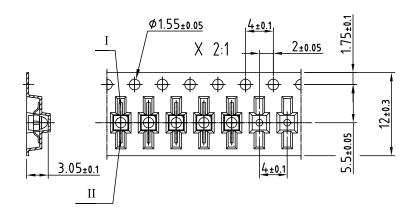


Leader and trailer tape:



Terminal position in tape

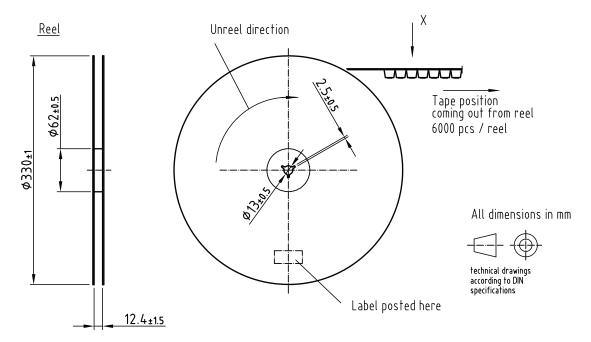
Device	Lead I	Lead II	
VEMT 2000	Collector Emitte		
VEMT 2500	Collector	Emirrei	
VEMD 2000			
VEMD 2500			
VSMB 2000	Cathode	Anode	
VSMG 2000	Carrioge	Alloue	
VSMF 2890 RG			
VSMB 294008 RG			
VSMY 2xxx			
	Anode	Cathode	
VSMF 288011 RG			



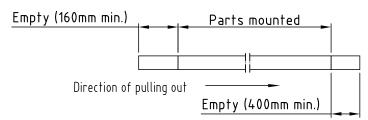
Drawing refers to following types: Reel dimensions and tape see table

Drawing-No.: 9.800-5100.01-4 Issue: preliminary, 11.07.19

TAPING AND REEL DIMENSIONS in millimeters: VSMY2890GX01

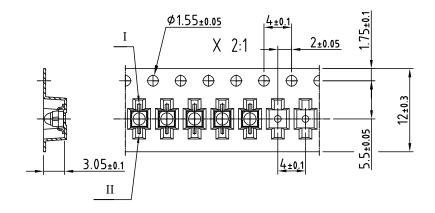


Leader and trailer tape:



Terminal position in tape

Device	Lead I	Lead II	
VSMB 2020			
VSMG 2020			
VEMD 2020	C-11-11-	A d .	
VEMD 2520	Cathode	Anode	
VSMF 2890 G			
VSMB 294008 G			
VEMT 2020	C . II	F= 144	
VEMT 2520	Collector	Emitter	
VSMY 2xxx			
	Anode	Cathode	
VSMF 288011 G			



Drawing refers to following types:

Reel dimensions and tape

Drawing-No.: 9.800-5091.01-4 Issue: preliminary, 11.07.19



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